



DXT2907A

60V PNP TRANSISTOR IN SOT89

Features

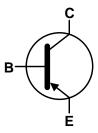
- BV_{CEO} > -60V
- Ideal for Medium Power Switching or Amplification Applications
- Ideally Suited for Automated Assembly Processes
- Complementary NPN Type Available (DXT2222A)
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

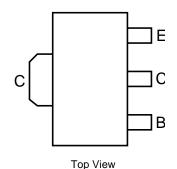
- Case: SOT89
- Case Material: Molded Plastic, "Green" Molding Compound UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 <a>®
- Weight: 0.072 grams (Approximate)







Device Symbol



Pin-Out

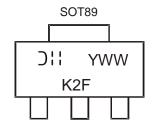
Ordering Information (Note 4)

Part Number	Marking	Reel Size (inches)	Tape Width (mm)	Quantity Per Reel
DXT2907A-13	K2F	13	12	2,500

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



K2F = Product Type Marking Code YWW = Date Code Marking Y = Last Digit of Year (ex: 5 = 2015) WW = Week Code (01 to 53)



Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-60	V
Collector-Emitter Voltage	V _{CEO}	-60	V
Emitter-Base Voltage	V _{EBO}	-5	V
Collector Current	Ic	-600	mA
Peak Collector Current	I _{CM}	-800	mA

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Power Dissipation	(Note 5)	D-	0.75	- w	
Power Dissipation	(Note 6)	P _D	1.2		
Thermal Resistance, Junction to Ambient Air	(Note 5)	D	166	°C/W	
Thermal Resistance, Junction to Ambient All	(Note 6)	$R_{ hetaJA}$	104		
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C		

ESD Ratings (Note 7)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Notes:

^{5.} For a device mounted with the exposed collector pad on minimum recommended pad layout 1oz copper that is on a single-sided 1.6mm FR-4 PCB; device is measured under still air conditions whilst operating in a steady-state.

Same as note 5, except the device is mounted with the exposed collector pad on 25mm x 25mm 1oz copper.
Refer to JEDEC specification JESD22-A114 and JESD22-A115.



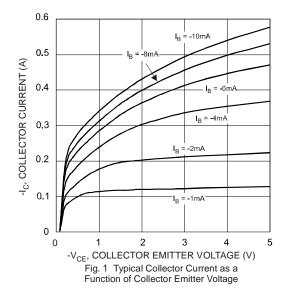
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

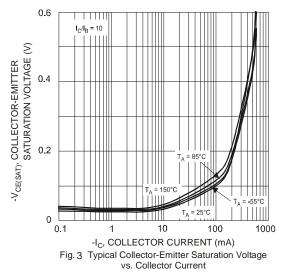
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS							
Collector-Base Breakdown Voltage	BV _{CBO}	-60	-120	_	V	I _C = -100μA	
Collector-Emitter Breakdown Voltage (Note 8)	BV _{CEO}	-60	-80	_	V	I _C = -10mA	
Emitter-Base Breakdown Voltage	BV _{EBO}	-5	-8.8	_	V	I _E = -100μA	
0 11 1 0 1 11 0		_	-1	-50	nA	V _{CB} = -50V	
Collector Cut-off Current	I _{CBO}	_	_	-50	μA	V _{CB} = -50V, T _A = +100°C	
Collector Cutoff Current	I _{CEX}	_	_	-50	nA	$V_{CE} = -30V, V_{EB(OFF)} = -0.5V$	
Emitter Cut-off Current	I _{EBO}	_	_	-50	nA	V _{EB} = -5V	
ON CHARACTERISTICS (Note 8)			I.	I.			
		75	208	_	_	$I_C = -100 \mu A, V_{CE} = -10 V$	
		100	207	_	-	I _C = -1mA, V _{CE} = -10V	
Static Forward Current Transfer Ratio	h _{FE}	100	202	_	_	$I_C = -10 \text{mA}, V_{CE} = -10 \text{V}$	
		100	169	300	_	I _C = -150mA, V _{CE} = -10V	
		50	103	_	_	I _C = -500mA, V _{CE} = -10V	
	V _{CE(SAT)}	_	-130	-400	mV	I _C = -150mA, I _B = -15mA	
Collector-Emitter Saturation Voltage		_	-0.4	-1.6	V	I _C = -500mA, I _B = -50mA	
	V _{BE(SAT))}	_	-0.86	-1.3	V	I _C = -150mA, I _B = -15mA	
Base-Emitter Saturation Voltage		_	-1	-2.6	V	I _C = -500mA, I _B = -50mA	
SMALL SIGNAL CHARACTERISTICS	<u> </u>					, ,	
Output Capacitance	C _{obo}	_	_	8	pF	V _{CB} = -10V, I _E = 0, f = 1MHz	
Input Capacitance	C _{ibo}	_	_	30	pF	$V_{EB} = -2V$, $f = 1MHz$, $I_{C} = 0$	
Current Gain-Bandwidth Product	f⊤	200	_	_	MHz	$V_{CE} = -20V, I_{C} = -50mA,$ f = 100MHz	
SWITCHING CHARACTERISTICS						_	
Turn-On Time	ton	_	_	45	ns	V _{CC} = -30V, I _C = -150mA, -I _{B1} = -15mA	
Delay Time	t _D	_	_	10	ns		
Rise Time	t _R			40	ns	-51	
Turn-Off Time	toff		_	100	ns	$V_{CC} = -6V, I_{C} = -150mA,$	
Storage Time	t _S		_	80	ns	I _{B1} =I _{B2} = -15mA	
Fall Time	t _F	_	_	30	ns	151 152 15	

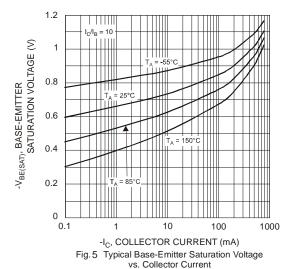
Note: 8. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%.



Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)







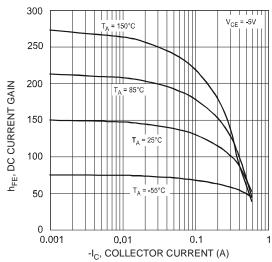
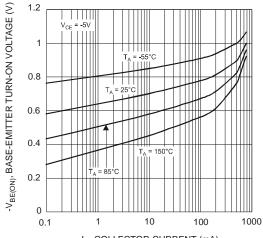


Fig. 2 Typical DC Current Gain vs. Collector Current



-I_C, COLLECTOR CURRENT (mA) Fig. 4 Typical Base-Emitter Turn-On Voltage vs. Collector Current

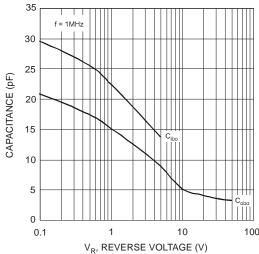
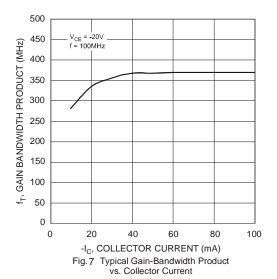
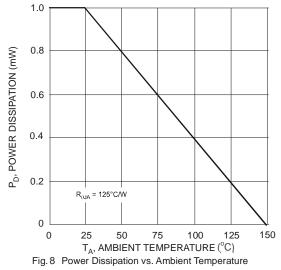


Fig. 6 Typical Capacitance Characteristics



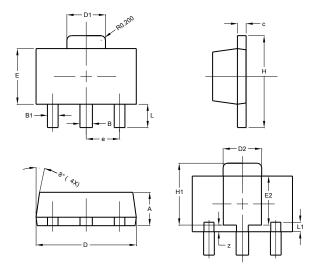






Package Outline Dimensions

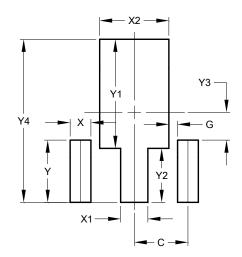
Please see AP02001 at http://www.diodes.com/_files/datasheets/ap02001.pdf for the latest version.



SOT89					
Dim	Min	Max	Тур		
Α	1.40	1.60	1.50		
В	0.50	0.62	0.56		
B1	0.42	0.54	0.48		
С	0.35	0.43	0.38		
D	4.40	4.60	4.50		
D1	1.62	1.83	1.733		
D2	1.61	1.81	1.71		
Е	2.40	2.60	2.50		
E2	2.05	2.35	2.20		
е	-	-	1.50		
Н	3.95	4.25	4.10		
H1	2.63	2.93	2.78		
L	0.90	1.20	1.05		
L1	0.327	0.527	0.427		
Z	0.20	0.40	0.30		
All Dimensions in mm					

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/_files/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
С	1.500
G	0.244
X	0.580
X1	0.760
X2	1.933
Y	1.730
Y1	3.030
Y2	1.500
Y3	0.770
Y4	4.530



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